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PMN25UN
20 V, 6 A N-channel Trench MOSFET
Rev. 1 - 28 July 2011
Product data sheet

## 1. Product profile

### 1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) small Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.
1.2 Features and benefits
■ Low threshold voltage

- Trench MOSFET technology
- Very fast switching


### 1.3 Applications

| $\square$ Relay driver | Low-side loadswitch |
| :--- | :--- |
| $\square$ High-speed line driver | $\square$ Switching circuits |

### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DS }}$ | drain-source voltage | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | - | - | 20 | V |
| $\mathrm{V}_{\mathrm{GS}}$ | gate-source voltage |  |  | -8 | - | 8 | V |
| $\mathrm{I}_{\mathrm{D}}$ | drain current | $\mathrm{V}_{\mathrm{GS}}=4.5 \mathrm{~V} ; \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ | [1] | - | - | 6 | A |
| Static characteristics |  |  |  |  |  |  |  |
| $\mathrm{R}_{\text {DSon }}$ | drain-source on-state resistance | $V_{G S}=4.5 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=6 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | - | 23 | 27 | $\mathrm{m} \Omega$ |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain $6 \mathrm{~cm}^{2}$.

## 2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| :--- | :--- | :--- | :--- | :--- |
| 1 | D | drain |  |  |
| 2 | D | drain |  |  |
| 3 | G | gate |  |  |
| 4 | S | source |  |  |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |  | Version |
| :--- | :--- | :--- | :--- |
|  | Name | Description | plastic surface-mounted package (TSOP6); 6 leads |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
| :--- | :--- |
| PMN25UN | T6 |

## 5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions |  | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {DS }}$ | drain-source voltage | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | - | 20 | V |
| $V_{G S}$ | gate-source voltage |  |  | -8 | 8 | V |
| $\mathrm{I}_{\mathrm{D}}$ | drain current | $V_{G S}=4.5 \mathrm{~V} ; \mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$ | [1] | - | 6 | A |
|  |  | $\mathrm{V}_{\mathrm{GS}}=4.5 \mathrm{~V} ; \mathrm{T}_{\text {amb }}=100^{\circ} \mathrm{C}$ | [1] | - | 3.6 | A |
| $\mathrm{I}_{\mathrm{DM}}$ | peak drain current | $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$; single pulse; $\mathrm{t}_{\mathrm{p}} \leq 10 \mu \mathrm{~s}$ |  | - | 24 | A |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$ | [2] | - | 530 | mW |
|  |  |  | [1] | - | 1330 | mW |
|  |  | $\mathrm{T}_{\text {sp }}=25^{\circ} \mathrm{C}$ |  | - | 6250 | mW |
| $\mathrm{T}_{\mathrm{j}}$ | junction temperature |  |  | -55 | 150 | ${ }^{\circ} \mathrm{C}$ |
| Tamb | ambient temperature |  |  | -55 | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |
| Source-drain diode |  |  |  |  |  |  |
| Is | source current | $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$ | [1] | - | 1.3 | A |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain $6 \mathrm{~cm}^{2}$.
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.


Fig 1. Normalized total power dissipation as a function of junction temperature


Fig 2. Normalized continuous drain current as a function of junction temperature

$\mathrm{I}_{\mathrm{DM}}=$ single pulse
(1) $t_{p}=100 \mu \mathrm{~s}$
(2) $\mathrm{t}_{\mathrm{p}}=1 \mathrm{~ms}$
(3) $t_{p}=10 \mathrm{~ms}$
(4) $\mathrm{t}_{\mathrm{p}}=100 \mathrm{~ms}$
(5) DC ; $\mathrm{T}_{\text {sp }}=25^{\circ} \mathrm{C}$
(6) $\mathrm{DC} ; \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$; drain mounting pad $6 \mathrm{~cm}^{2}$

Fig 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

## 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {th( }}^{\text {(-a) }}$ ) | thermal resistance from junction to ambient | in free air | [1] | - | 204 | 235 | K/W |
|  |  |  | [2] | - | 82 | 94 | K/W |
| $\mathrm{R}_{\mathrm{th}(\text { (-sp) }}$ | thermal resistance from junction to solder point |  |  | - | 17 | 20 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain $6 \mathrm{~cm}^{2}$.


FR4 PCB, standard footprint
Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values


FR4 PCB, mounting pad for drain $6 \mathrm{~cm}^{2}$
Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 7. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Static characteristics |  |  |  |  |  |  |
| $V_{(B R) D S S}$ | drain-source breakdown voltage | $\mathrm{I}_{\mathrm{D}}=250 \mu \mathrm{~A} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | 20 | - | - | V |
| $V_{\text {GSth }}$ | gate-source threshold voltage | $\mathrm{I}_{\mathrm{D}}=250 \mu \mathrm{~A} ; \mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{G S} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | 0.4 | 0.7 | 1 | V |
| $\mathrm{I}_{\text {DSS }}$ | drain leakage current | $V_{D S}=20 \mathrm{~V} ; \mathrm{V}_{G S}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | - | 1 | $\mu \mathrm{A}$ |
|  |  | $V_{D S}=20 \mathrm{~V} ; \mathrm{V}_{G S}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$ | - | - | 25 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {GSS }}$ | gate leakage current | $V_{G S}=8 \mathrm{~V} ; \mathrm{V}_{\text {DS }}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | - | 100 | nA |
|  |  | $V_{G S}=-8 \mathrm{~V} ; \mathrm{V}_{\text {DS }}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | - | 100 | nA |
| $\mathrm{R}_{\text {DSon }}$ | drain-source on-state resistance | $V_{G S}=4.5 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=6 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 23 | 27 | $\mathrm{m} \Omega$ |
|  |  | $V_{G S}=4.5 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=6 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$ | - | 33 | 40 | $\mathrm{m} \Omega$ |
|  |  | $\mathrm{V}_{G S}=2.5 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=5 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 28 | 35 | $\mathrm{m} \Omega$ |
|  |  | $V_{G S}=1.8 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=4 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 37 | 58 | $\mathrm{m} \Omega$ |
| $\mathrm{g}_{\mathrm{fs}}$ | forward transconductance | $V_{D S}=10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=6 \mathrm{~A} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 24 | - | S |


| Dynamic characteristics |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{Q}_{\mathrm{G} \text { (tot) }}$ | total gate charge | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V} ; \mathrm{I}_{\mathrm{D}}=6 \mathrm{~A} ; \mathrm{V}_{\mathrm{GS}}=4.5 \mathrm{~V}$; | - | 6.4 | 10 | nC |
| Qgs | gate-source charge | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 1 | - | nC |
| QGD | gate-drain charge |  |  | 1.6 | - | nC |
| $\mathrm{C}_{\text {iss }}$ | input capacitance | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V} ; \mathrm{f}=1 \mathrm{MHz} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$; | - | 470 | - | pF |
| $\mathrm{C}_{\text {oss }}$ | output capacitance | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 125 | - | pF |
| $\mathrm{C}_{\text {rss }}$ | reverse transfer capacitance |  | - | 72 | - | pF |
| $\mathrm{t}_{\mathrm{d}(\mathrm{on})}$ | turn-on delay time | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V} ; \mathrm{V}_{\mathrm{GS}}=4.5 \mathrm{~V} ; \mathrm{R}_{\mathrm{G}(\mathrm{ext})}=6 \Omega$; | - | 9 | - | ns |
| $\mathrm{t}_{\mathrm{r}}$ | rise time | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} ; \mathrm{I}_{\mathrm{D}}=6 \mathrm{~A}$ | - | 35 | - | ns |
| $\mathrm{t}_{\mathrm{d} \text { (off) }}$ | turn-off delay time |  | - | 109 | - | ns |
| $\mathrm{t}_{\mathrm{f}}$ | fall time |  | - | 59 | - | ns |
| Source-drain diode |  |  |  |  |  |  |
| $\mathrm{V}_{\text {SD }}$ | source-drain voltage | $\mathrm{I}_{\mathrm{S}}=1.3 \mathrm{~A} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | - | 0.7 | 1.2 | V |



Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$
(1) $\mathrm{V}_{\mathrm{GS}}=1.4 \mathrm{~V}$
(2) $\mathrm{V}_{G S}=1.6 \mathrm{~V}$
(3) $\mathrm{V}_{\mathrm{GS}}=1.8 \mathrm{~V}$
(4) $\mathrm{V}_{\mathrm{GS}}=2.2 \mathrm{~V}$
(5) $\mathrm{V}_{\mathrm{GS}}=2.5 \mathrm{~V}$
(6) $\mathrm{V}_{\mathrm{GS}}=3.0 \mathrm{~V}$
(7) $\mathrm{V}_{\mathrm{GS}}=4.5 \mathrm{~V}$

Fig 8. Drain-source on-state resistance as a function of drain current; typical values

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} ; \mathrm{V}_{\mathrm{DS}}=5 \mathrm{~V}$
(1) minimum values
(2) typical values
(3) maximum values

Fig 7. Sub-threshold drain current as a function of gate-source voltage

$\mathrm{I}_{\mathrm{D}}=6 \mathrm{~A}$
(1) $\mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C}$
(2) $T_{j}=25^{\circ} \mathrm{C}$

Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

(1) $T_{j}=25^{\circ} \mathrm{C}$
(2) $\mathrm{T}_{\mathrm{i}}=150^{\circ} \mathrm{C}$

Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$\mathrm{I}_{\mathrm{D}}=0.25 \mathrm{~mA} ; \mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{\mathrm{GS}}$
(1) maximum values
(2) typical values
(3) minimum values

Fig 12. Gate-source threshold voltage as a function of junction temperature


Fig 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

$\mathrm{f}=1 \mathrm{MHz} ; \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$
(1) $\mathrm{C}_{\text {iss }}$
(2) $\mathrm{C}_{\text {oss }}$
(3) $\mathrm{C}_{\text {rss }}$

Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$\mathrm{I}_{\mathrm{D}}=6.0 \mathrm{~A} ; \mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V} ; \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$
Fig 14. Gate-source voltage as a function of gate charge; typical values


Fig 15. Gate charge waveform definitions

$V_{G S}=0 \mathrm{~V}$
(1) $T_{j}=150^{\circ} \mathrm{C}$
(2) $T_{j}=25^{\circ} \mathrm{C}$

Fig 16. Source current as a function of source-drain voltage; typical values

## 8. Test information



Fig 17. Duty cycle definition

## 9. Package outline


detail X

DIMENSIONS (mm are the original dimensions)

| UNIT | $\mathbf{A}$ | $\mathbf{A}_{\mathbf{1}}$ | $\mathbf{b p}$ | $\mathbf{c}$ | $\mathbf{D}$ | $\mathbf{E}$ | $\mathbf{e}$ | $\mathbf{H}_{\mathbf{E}}$ | $\mathbf{L}_{\mathbf{p}}$ | $\mathbf{Q}$ | $\mathbf{v}$ | $\mathbf{w}$ | $\mathbf{y}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.1 | 0.1 | 0.40 | 0.26 | 3.1 | 1.7 | 0.95 | 3.0 | 0.6 | 0.33 | 0.2 | 0.2 | 0.1 |
|  | 0.9 | 0.013 | 0.25 | 0.10 | 2.7 | 1.3 | 0.5 | 0.2 | 0.23 |  |  |  |  |


| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN <br> PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  | $-05-11-07$ |
| SOT457 |  |  | SC-74 |  | $06-03-16$ |  |

Fig 18. Package outline SOT457 (TSOP6)

## 10. Soldering



Fig 19. Reflow soldering footprint for SOT457 (TSOP6)


QIVIA solder lands
=--- solder resist
$1---1$ occupied area

Dimensions in mm
preferred transport direction during soldering
sot457_fw
Fig 20. Wave soldering footprint for SOT457 (TSOP6)

## 11. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| :--- | :--- | :--- | :--- | :--- |
| PMN25UN v. 1 | 20110728 | Product data sheet | - | - |

## 12. Legal information

### 12.1 Data sheet status

| Document status $\underline{[1]}$ [2] | Product status $\underline{[3]}$ | Definition |
| :--- | :--- | :--- |
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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